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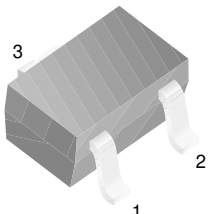
FJX4010R

Switching Application (Bias Resistor Built In)

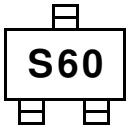
- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R=10KΩ)
- Complement to FJX3010R



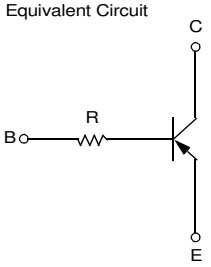
SOT-323

1. Base 2. Emitter 3. Collector

Marking



Equivalent Circuit



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-40	V
V_{CEO}	Collector-Emitter Voltage	-40	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current	-100	mA
P_C	Collector Power Dissipation	200	mW
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C= -100μA, I_E=0	-40			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_E= -1mA, I_B=0	-40			V
I_{CBO}	Collector Cut-off Current	V_{CB}= -30V, I_E=0			-0.1	μA
h_{FE}	DC Current Gain	V_{CE}= -5V, I_C= -1mA	100		600	
V_{CE} (sat)	Collector-Emitter Saturation Voltage	I_C= -10mA, I_B= -1mA			-0.3	V
C_{ob}	Output Capacitance	V_{CB}= -10V, I_E=0 f=1MHz		5.5		pF
f_T	Current Gain Bandwidth Product	V_{CE}= -10V, I_C= -5mA		200		MHz
R	Input Resistor		7	10	13	KΩ

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Typical Characteristics

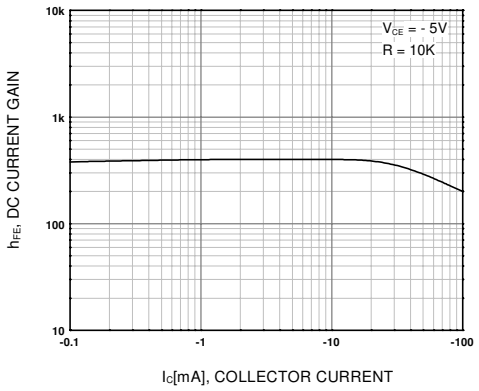

Figure 1. DC current Gain

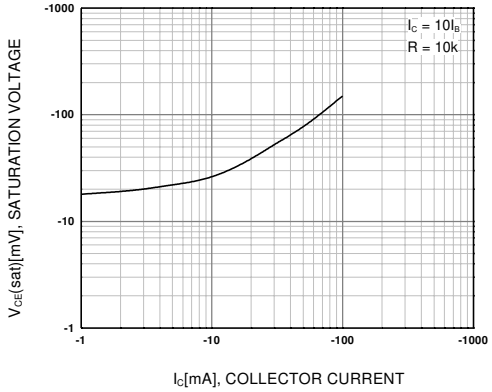

Figure 2. Collector-Emitter Saturation

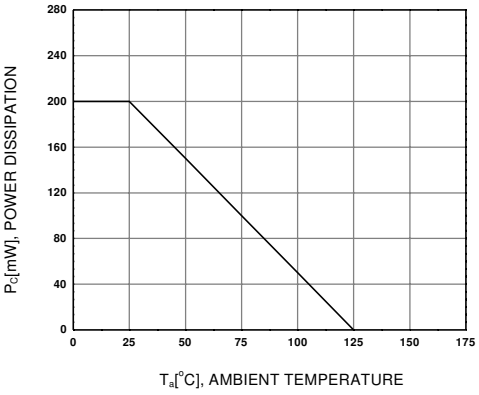

Figure 3. Power Derating

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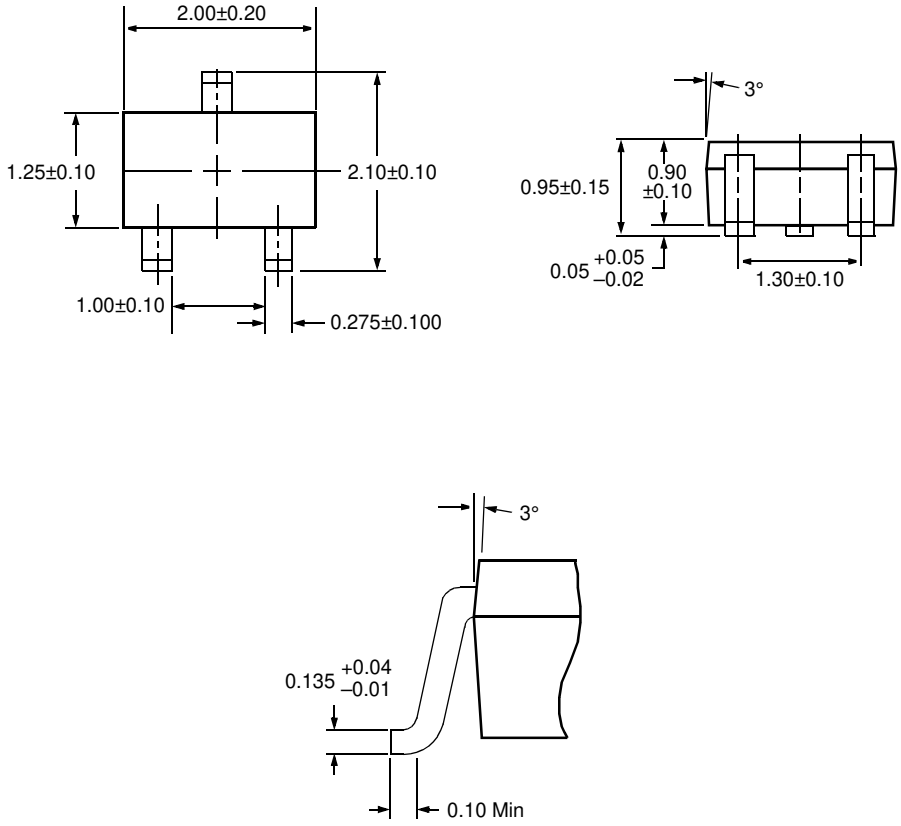
Package Dimensions

SOT-323



Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E^2CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C™	OCX™	RapidConfigure™	UHC™
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The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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